Analog Power AM7340N

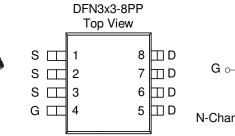
## N-Channel 40-V (D-S) MOSFET

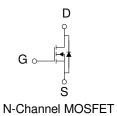
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low r <sub>DS(on)</sub> provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY					
$oxed{V_{DS}\left(V ight)} oxed{r_{DS(on)} m(\Omega)} oxed{I_{D}} \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $					
40	$5.5 @ V_{GS} = 10V$	21			
40	7 @ V <sub>GS</sub> = 4.5V	19			





<b>RoHS</b>
COMPLIANT
HALOGEN
FRFF

ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Maximum	Units			
Drain-Source Voltage			40	V		
Gate-Source Voltage			±20	v		
	T <sub>A</sub> =25°C	Τ_	21			
Continuous Drain Current <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	17	A		
Pulsed Drain Current <sup>b</sup>			±40			
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	2.9	A		
Danie Diadicali	$T_A=25^{\circ}C$	D.	3.5	$\mathbf{w}$		
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	Гр	2	• • • • • • • • • • • • • • • • • • • •		
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
a	t <= 10 sec	ъ	35	°C/W			
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	R <sub>0JA</sub>	81	°C/W			

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## Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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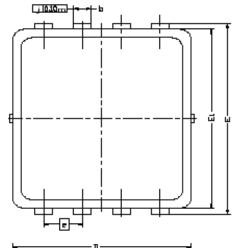
SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
Donomoton	Cymbol	Took Conditions	Limits			T I24	
Parameter	Symbol	Test Conditions		Typ	Max	Unit	
Static	-				-		
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	<sup>1</sup> DSS	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25	uA	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			A	
Drain-Source On-Resistance <sup>A</sup>		$V_{GS} = 10 \text{ V}, I_D = 1 \text{ A}$			5.5	mΩ	
Drain-Source On-Resistance	$r_{\mathrm{DS(on)}}$	$V_{GS} = 4.5 \text{ V}, I_D = 1 \text{ A}$			7	1115.2	
Forward Tranconductance <sup>A</sup>	${f g}_{ m fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 1 \text{ A}$		40		S	
Diode Forward Voltage	$V_{SD}$	$I_S = 1 A, V_{GS} = 0 V$		0.7		V	
Dynamic <sup>b</sup>							
Total Gate Charge	$Q_{\mathrm{g}}$	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$		30			
Gate-Source Charge	$Q_{\mathrm{gs}}$	$I_{DS} = 10 \text{ V}, V_{GS} = 4.3 \text{ V},$ $I_{D} = 1 \text{ A}$		9		nC	
Gate-Drain Charge	$Q_{\mathrm{gd}}$	$I_{\rm D} = I A$		10			
Turn-On Delay Time	$t_{d(on)}$			9			
Rise Time	t <sub>r</sub>	$V_{DD} = 10 \text{ V}, R_L = 6 \Omega \text{ , } ID = 1 \text{ A},$		10		, C	
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = 10 \text{ V}$		100		nS	
Fall-Time	$t_{\rm f}$			30			

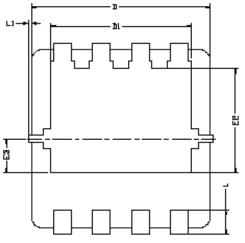
## Notes

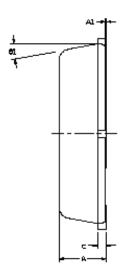
- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information







DIM.	MIL	HILLIMETERS			INCHES			
יויודת	MIN	NOM	MAX	MIN	NDM	MAX		
Α	0,700	0'80	0.900	0.0276	0.0315	0.0354		
A1	0.00	-	0.05	0.000		0.002		
la	0.24	0.30	0.35	0.009	0.012	0.014		
C	0.10	0.152	0,25	0,004	0,006	0,010		
ם	(3	3.00 BSC			0.118 BSC			
D1	2.35 BCC			0.093 BSC				
Ε	3	3,20 BSC			0.126 BSC			
E1	3.00 BSC			0.118 BSC				
E5	1	1.75 BSC			0.069 BSC			
E3	0.575 BSC			0.	023 BS	C.		
6	0.65 BSC			0.026 BSC				
L	0,30	0,40	0,50	0.0118	0.0157	0.0197		
L1			0.100	D		0.004		
91	٥°	10*	12*	0*	10°	12*		